



SCCE7V012N1

Ultra-low Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

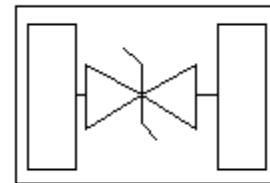
● Description

The SCCE7V012N1 is designed with SSC Punch-Through process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, USB 3.0 super speed, VGA, DVI, HDMI,SDI and other high speed line applications.

● Feature

- ◇ 50W peak pulse power ($t_P = 8/20\mu s$)
- ◇ DFN1006 Package
- ◇ Working voltage: 7V
- ◇ Low clamping voltage
- ◇ Low capacitance
- ◇ RoHS compliant transient protection for high speed data lines to IEC61000-4-2(ESD) $\pm 25kV$ (air), $\pm 25kV$ (contact)

● PIN configuration



Topview

● Applications

- ◇ DVI & HDMI Port Protection
- ◇ Serial and Parallel Ports
- ◇ Projection TV
- ◇ Notebooks, Desktops, Servers
- ◇ Solid-state Punch-Through TVS Process technology Portable instrumentation

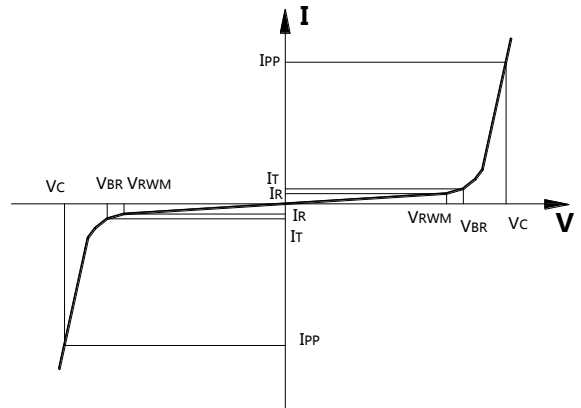
● Mechanical data

- ◇ Lead finish: 100% matte Sn(Tin)
- ◇ Mounting position: Any
- ◇ Qualified max reflow temperature: 260 °C
- ◇ Device meets MSL 1 requirements
- ◇ Pure tin plating: 7 ~ 17 um
- ◇ Pin flatness: $\leq 3mil$



● Electronic Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C	Junction Capacitance



● Absolute maximum rating @TA=25°C

Symbol	Parameter	Value	Units
P_{PP}	Peak Pulse Power (8/20 μ S)	50	W
T_{STG}	Storage Temperature	-55/+150	°C
T_J	Operating Temperature	-55/+150	°C

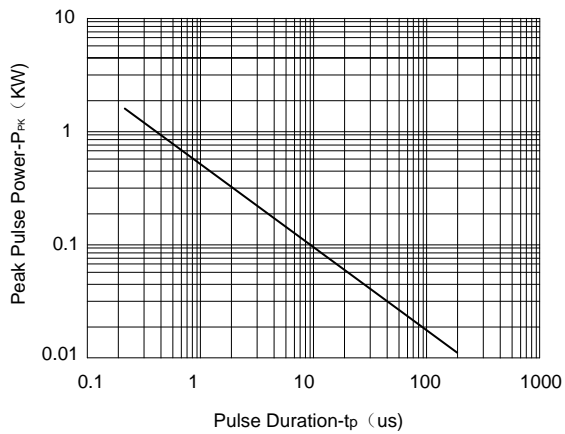
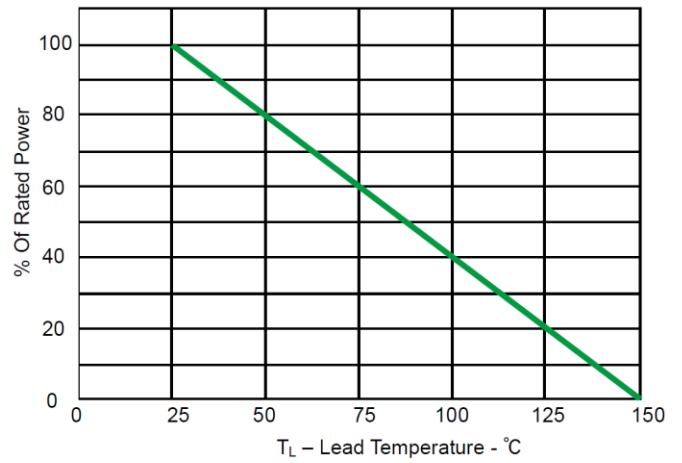
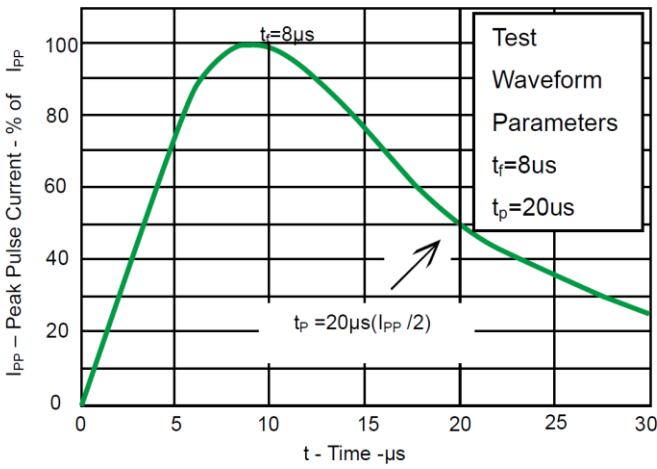
● Electrical Characteristics @TA=25°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}			7		V
Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	8.5	7.4	10	V
Reverse Leakage Current	I_R	$V_{RWM} = 5.0\text{V}, T = 25^\circ\text{C}$			1	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}, t_P = 8/20\mu\text{s}$		7		V
Clamping Voltage	V_C	$I_{PP} = 3\text{A}, t_P = 8/20\mu\text{s}$			15	V
Junction Capacitance	C_J	$V_R = 0\text{V}, f = 1\text{MHz}$		7	12	pF

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- **Typical Performance Characteristics**

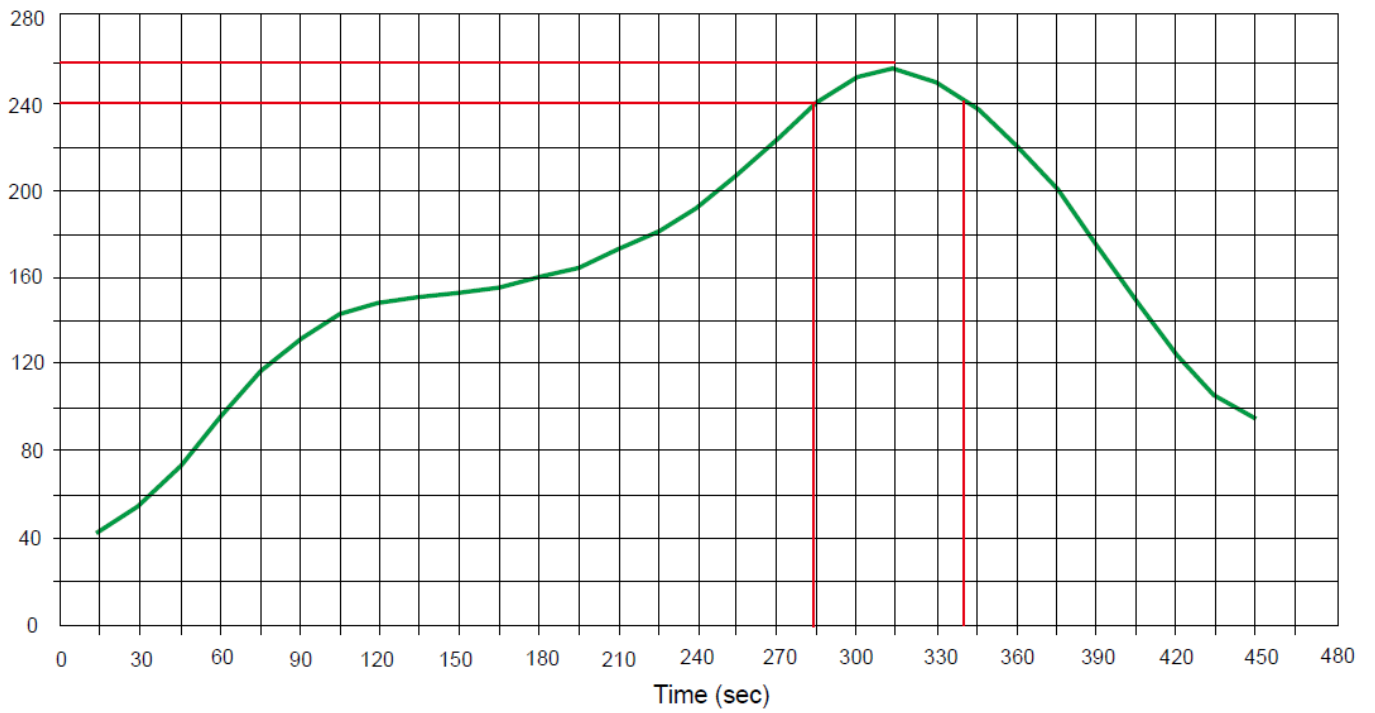


Non-Repetitive Peak Pulse Power vs. Pulse Time



- **Solder Reflow Recommendation**

Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec





- **Package Information**

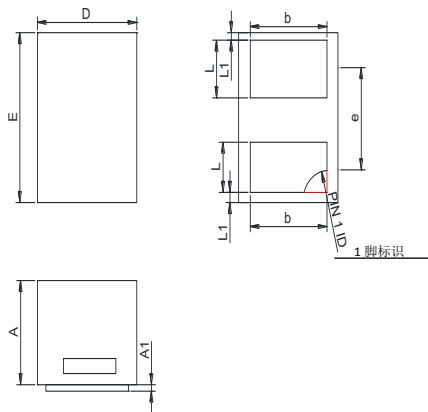
Ordering Information

Device	Package	Qty per Reel	Reel Size
SCCE7V022N1	DFN1006-2L	10000	7 Inch

Mechanical Data

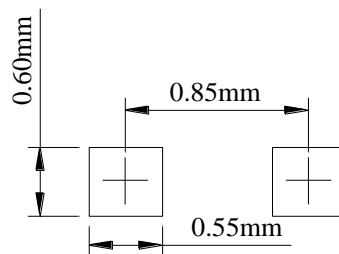
Case:DFN1006

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters	
	Min	Max
A	0.30	0.50
A1	0.00	0.05
D	0.55	0.65
E	0.95	1.05
b	0.25	0.60
e	0.65TYP	
L	0.15	0.35
L1	0.05REF	

Recommended Pad outline





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